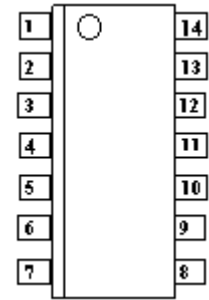


**DESCRIPTION**

These low capacitance diode arrays are multiple, discrete, isolated junctions fabricated by a planar process and mounted in a 14-PIN package for use as steering diodes protecting up to eight I/O ports from ESD, EFT, or surge by directing them either to the positive side of the power supply line or to ground (see figure 1). An external TVS diode may be added between the positive supply line and ground to prevent overvoltage on the supply rail. They may also be used in fast switching core-driver applications. This includes computers and peripheral equipment such as magnetic cores, thin-film memories, plated-wire memories, etc., as well as decoding or encoding applications. These arrays offer many advantages of integrated circuits such as high-density packaging and improved reliability. This is a result of fewer pick and place operations, smaller footprint, smaller weight, and elimination of various discrete packages that may not be as user friendly in PC board mounting. They are available with either Tin-Lead plating terminations or as RoHS Compliant with annealed matte-Tin finish by adding an "e3" suffix to the part number.

**APPEARANCE**



Top Viewing Pin Layout

**IMPORTANT:** For the most current data, consult MICROSEMI's website: <http://www.microsemi.com>

**FEATURES**

- 16 Diode Array / protects 8 lines
- Molded 14-Pin SOIC Package
- UL 94V-0 Flammability Classification
- Low Capacitance 1.5 pF per diode
- Switching speeds less than 5 ns
- RoHS Compliant devices available by adding "e3" suffix
- IEC 61000-4 compatible
  - 61000-4-2 (ESD): Air 15kV, contact – 8 kV
  - 61000-4-4 (EFT): 40A – 5/50 ns
  - 61000-4-5 (surge): 12A, 8/20 μs

**APPLICATIONS / BENEFITS**

- Low capacitance steering diode protection for high frequency data lines
- RS-232 & RS-422 Interface Networks
- Ethernet: 10 Base T
- Computer I / O Ports
- LAN
- Switching Core Drivers

**MAXIMUM RATINGS**

- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Forward Surge Current: 2 Amps (8.3 ms)  
12 Amps (8/20 μs)
- Continuous Forward Current: 400 mA (one diode)
- Power Dissipation (P<sub>D</sub>): 1500 mW (total)
- Solder temperatures: 260°C for 10 s (maximum)

**MECHANICAL AND PACKAGING**

- CASE: Void-free transfer molded thermosetting epoxy body meeting UL94V-0 flammability classification
- TERMINALS: Tin-Lead or RoHS Compliant annealed matte-Tin plating solderable per MIL-STD-750 method 2026
- MARKING: MSC logo, MMAD1104 or MMAD1104e3 and date code. Pin #1 is to the left of the dot or indent on top of package
- WEIGHT: 0.127 grams (approximate)
- Tape & Reel packaging: 2500 pcs (STANDARD)
- Carrier tube packaging: 55 pcs

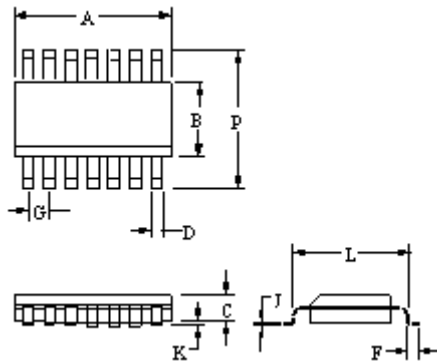
**ELECTRICAL CHARACTERISTICS PER LINE @ 25°C Unless otherwise specified**

PART NUMBER	BREAKDOWN VOLTAGE V <sub>BR</sub> @ I <sub>BR</sub> = 100μA	WORKING PEAK REVERSE VOLTAGE V <sub>RWM</sub>	LEAKAGE CURRENT I <sub>R</sub> T <sub>A</sub> = 25°C		LEAKAGE CURRENT I <sub>R</sub> T <sub>A</sub> = 150°C		CAPACITANCE C @ 0 V	REVERSE RECOVERY TIME t <sub>r</sub>	FORWARD VOLTAGE V <sub>F</sub> I <sub>F</sub> = 10 mA	FORWARD VOLTAGE V <sub>F</sub> I <sub>F</sub> = 100 mA
	V	V	μA		μA		pF	ns	V	V
	MIN	MAX	MAX	@V <sub>R</sub>	MAX	@V <sub>R</sub>	TYP	MAX	MAX	MAX
MMAD1104 MMAD1104e3	90	75	0.200	20	300	20	1.5	5.0	1.00	1.20

**SYMBOLS & DEFINITIONS**

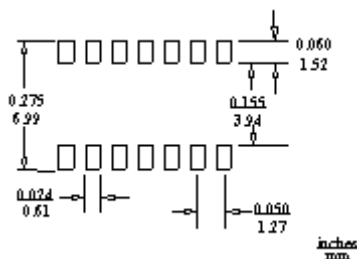
Symbol	Definition
$V_{BR}$	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.
$V_{RWM}$	Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range.
$V_F$	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.
$I_R$	Maximum Leakage Current: The maximum leakage current that will flow at the specified voltage and temperature.
C	Capacitance: The capacitance of the TVS as defined @ 0 volts at a frequency of 1 MHz and stated in picofarads.

**OUTLINE AND CIRCUIT**

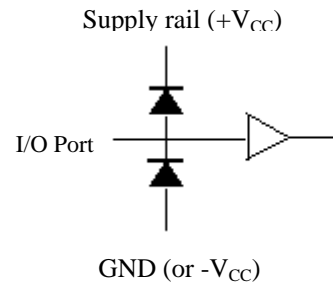


DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.336	0.344	8.53	8.74
B	0.150	0.158	3.81	4.01
C	0.053	0.069	1.35	1.75
D	0.011	0.021	0.28	0.53
F	0.016	0.050	0.41	1.27
G	0.050 BSC		01.27 BSC	
J	0.006	0.010	0.15	0.25
K	0.004	0.008	0.10	0.20
L	0.189	0.206	4.80	5.23
P	0.228	0.244	5.79	6.19

**OUTLINE**

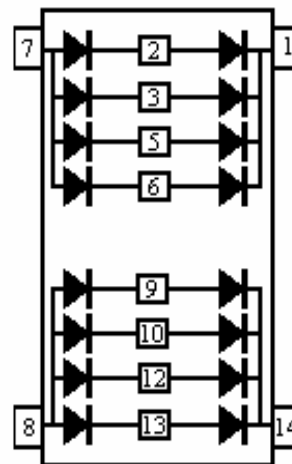


**PAD LAYOUT**



**STEERING DIODE APPLICATION**

figure 1



**CIRCUIT CONFIGURATION**